

R-C Thermal Model Parameters

DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included.

Note:

For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).

R-C THERMAL MODEL FOR TANK CONFIGURATION



R-C VALUES FOR TANK CONFIGURATION					
Thermal Resistance (°C/W)					
Junction to	Ambient Ch1	Ambient Ch2	Case	Foot Ch1	Foot Ch2
RT1	20.2615	17.1236	N/A	12.5201	15.8334
RT2	31.3084	19.9107	N/A	15.0130	11.0107
RT3	3.7262	12.0169	N/A	3.9622	4.2755
RT4	54.7039	60.9488	N/A	8.5047	8.8804
Thermal Capacitance (Joules/°C)					
Junction to	Ambient Ch1	Ambient Ch2	Case	Foot Ch1	Foot Ch2
CT1	8.5568 m	42.8107 m	N/A	42.5506 m	79.4131 m
CT2	56.4965 m	53.9821 m	N/A	5.0473 m	3.9493 m
CT3	982.5193 u	1.0904 m	N/A	283.6484 u	201.5379 u
CT4	1.6094	1.2903	N/A	3.7356 m	38.1364 m

This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

R-C THERMAL MODEL FOR FILTER CONFIGURATION**R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance (°C/W)					
Junction to	Ambient Ch1	Ambient Ch2	Case	Foot Ch1	Foot Ch2
RF1	4.3391	10.0822	N/A	4.9638	5.6086
RF2	24.2012	17.6858	N/A	17.1582	14.8875
RF3	28.5502	21.4399	N/A	12.7026	16.4891
RF4	52.9095	60.7921	N/A	5.1754	3.0148
Thermal Capacitance (Joules/°C)					
Junction to	Ambient Ch1	Ambient Ch2	Case	Foot Ch1	Foot Ch2
CF1	702.8591 u	775.6964 u	N/A	234.6154 u	233.6176 u
CF2	6.3258 m	14.6743 m	N/A	1.6557 m	4.1080 m
CF3	48.8845 m	14.1282 m	N/A	7.7587 m	38.0499 m
CF4	1.5877	1.1823	N/A	145.8204 m	568.0203 m

Note: NA indicates not applicable

Reference:

[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya. IEEE / SEMITHERM 2002



